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Form PTO 1449	ATTY. DOCKET NUMBER HITA.0143	SERIAL NUMBER To Be Assigned	22
U.S. Department of Commerce Patent and Trademark Office	APPLICANT SHIMAMOTO et al.		
Information Disclosure Statement by Applicant	FILING DATE Concurrently Herewith	2823	2 S

U.S. Patent Documents

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Examiner		DOCUMENT	DATE	Name	CLASS	SUBC	FILING DATE
Initial		Number			1	LASS	
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Foreign Patent Documents

Examiner	DOCUMENT NUMBER	FILING DATE	COUNTRY	CLAS	SUB-	Trans	LATION
Initial			ĺ	s	CLASS	Yes	No
KN.	6-244364 J	2/17/93	Japan			Abstract	Х

Other Documents (Including Author, Title, Date Pertinent Pages, Etc.)

K.N.		Masahiko Hiratani, Toshihide Nabatame, Yuichi Matsui, Yasuhiro Shimamoto, Yoshitaka Sasago, Yoshitaka Nakamura, Yuzuru Ohji, Isamu Asano and Shinichiro Kimura, "A Conformal Ruthenium electrode for MIM Capacitors in Gbit DRAMs Using the CVD Technology Based on Oxygen-Controlled Surface Reaction", 2000 Symposium on VLSI Technology Digest of Technical Papers, pp. 102-103					
EXAMPLE DATE CONSIDERED D.5 /01 / 03							
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